

PATENT  
0941-0860P

IN THE U.S. PATENT AND TRADEMARK OFFICE

Applicant: LEE, Yueh-Chuan et al      Conf.:  
Appl. No.: NEW      Group:  
Filed: October 30, 2003      Examiner:  
For: SEMICONDUCTOR STRUCTURE WITH PARTIALLY  
ETCHED GATE AND METHOD OF FABRICATING THE  
SAME

PRELIMINARY AMENDMENT

Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

October 30, 2003

Sir:

The following preliminary amendments and remarks are respectfully submitted in connection with the above-identified application.

This amendment includes:

Amendments to the Specification

Remarks